NSN 5961-00-088-4690

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-088-4690 **Inclosure Material:** Metal **Overall Length:** 1.218 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.683 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse voltage, peak **Current Rating Per Characteristic:** 110.00 milliamperes gate trigger current, dc **Maximum Operating Tempurature Per Measurement Point:** 87.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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